



PTO/SB/08A/B (09-08)
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Substitute for form 1449/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Complete if Known	
				Application Number	10/573,463 Cont. #9267 10/573463
				Filing Date	December 1, 2006
				First Named Inventor	Eric Pascal Feltin
				Art Unit	2842 2823
				Examiner Name	Not Yet Assigned — Singal
Sheet	1	of	1	Attorney Docket Number	REGIM 3.3-089

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
		Country Code ⁴ -Number ⁵ -Kind Code ⁶ (if known)				

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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
/AS	CA	Frayssinet, Beaumont, Faurie, Gibart, Makkai, Lefebvre and Valvin, "Micro Epitaxial Lateral Overgrowth of GaN/sapphire by Metal Organic Vapour Phase Epitaxy", MRS Internet J. Nitride Semicond. Res. 7, 8 (2002), pages 1-7.	

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¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

Examiner Signature	/Ankush Singal/	Date Considered	05/18/2007
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				Application Number	10/573,463-Genf. #9267
				Filing Date	December 1, 2006
				First Named Inventor	Eric Pascal Feltn
				Art Unit	2812 2822
				Examiner Name	Not Yet Assigned <i>Singal</i>
Sheet	1	of	1	Attorney Docket Number	REGIM 3.3-089

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/AS/	CA	Beaumont B., Vennegues P., Gibart P., "Epitaxial Overgrowth of GaN", Phys. Stat. sol. (b) 227, No. 1, pgs. 1-43, 2001.		
/AS/	CB	Lahreche, Vennegues, Beaumont and Gibart, "Growth of high-quality GaN by low pressure metal-organic vapor phase epitaxy (LP-MOVPE) from 3D islands and lateral overgrowth", Journal of Crystal Growth 205, 245 (1999).		
/AS/	CC	Mathis et al., "Modeling of threading dislocation reduction in growing GaN layers", Journal of Crystal Growth, 231, pgs 371-390, (2001).		

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Examiner Signature	/Ankush Singal/	Date Considered	05/18/2007
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Substitute for form 1449/PTO			Complete If Known		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)			Application Number	10/573,463	
			Filing Date	March 24, 2006	
			First Named Inventor	Eric Pascal Felton	
			Art Unit	N/A R 2823	
			Examiner Name	Not Yet Assigned <i>Singh</i>	
Sheet	1	of	1	Attorney Docket Number	REGIM 3.3-089

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/AS/	AA*	US-2001/0022154-A1	09-20-2001	Cho et al.	
	AB*	US-5,919,305-A	07-06-1999	Solomon	
	AC*	US-6,559,075-B1	05-06-2003	Kelly et al.	
	AD*	US-2002/182889-A1	12-05-2002	Solomon et al.	
	AE*	US-6,071,795-A	06-06-2000	Cheung et al.	
	AF*	US-6,146,457-A	11-14-2000	Solomon	
/AS/	AG*	US-2003/0024472-A1	02-06-2003	Maruska et al.	

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		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	MM-DD-YYYY			
/AS/	BA	EP-1 246 233-A2 ✓	10-02-2002	Hitachi Cable		✓
↓	BB	WO-96/41906-A ✓	12-27-1996	Advanced Tech Materials		✓
	BC	EP-1 245 702-A ✓	10-02-2002	Hitachi Cable, Ltd.		✓
	BD	EP-1 041 610-A1 ✓	10-04-2002	Sumitomo Electric Industries		✓
/AS/	BE	WO-03/062507-A ✓	07-31-2003	S.O.I.Tec Silicon Insulator Technologies		✓

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